

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Surface-mounted package
- ☒ Fast switching speed
- ☒ SGT technology
- ☒ 100% avalanche tested

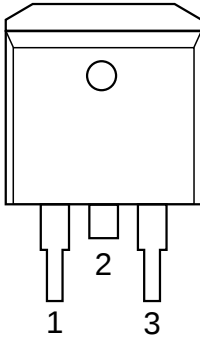
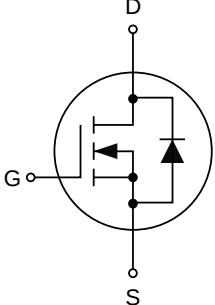
1.2 Applications

- ☒ DC/DC converter
- ☒ Motor drives
- ☒ Power switch
- ☒ BMS

1.3 Quick reference

- ☒ $BV \geq 60\text{ V}$
- ☒ $P_D \leq 250\text{ W}$
- ☒ $I_D \leq 286\text{ A}$
- ☒ $R_{DS(ON)} \leq 1.8\text{ m}\Omega @V_{GS}=10\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO-263	
2	Drain(D)		
3	Source(S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	Drain-Source Voltage	T _C =25℃	60	-	V
V _{GS}	Gate-Source Voltage	T _C =25℃	-	±20	V
I _D	Continuous Drain Current	T _C =25℃, V _{GS} =10 V ^[1]	-	286	A
		T _C =100℃, V _{GS} =10 V	-	181	A
I _{DM}	Pulsed Drain Current ^[2]	T _C =25℃, V _{GS} =10 V	-	1144	A
P _D	Power Dissipation	T _C =25℃	-	250	W
E _{AS}	Single Pulsed Avalanche Energy	V _{DD} =30 V, L=0.3 mH	-	920	mJ
T _J , T _{stg}	Operating Junction and Storage Temperature Range		-55	175	℃
R _{θJA}	Thermal Resistance-Junction to Ambient ^[3]		-	50	℃/W
R _{θJC}	Thermal Resistance-Junction to Case		-	0.5	

Notes:

1. Package limited.
2. Pulse width limited by maximum junction temperature.
3. R_{θJA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5"x1.5" board of FR-4 material.

4. Marking Information

Product Name	Marking
KJ018N06D	KJ018N06D XXXXXX-X

5. Ordering Code

Product Name	Package	Reel size	Tape width	Quantity (pcs)
KJ018N06D	TO-263	13"	24 mm	800

Note: KUAJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C).

6. Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _{DS} =250 μA	60	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250 μA	2	3	4	V
I _{DSS}	Drain Leakage Current	V _{DS} =60 V, V _{GS} =0 V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{DS} =0 V, V _{GS} =±20 V	-	-	±100	nA
R _{DS(ON)} ^a	On-State Resistance	V _{GS} =10 V, I _{DS} =50 A	-	1.5	1.8	mΩ
R _G	Gate resistance	f=1 MHz		2		Ω
Diode Characteristics						
V _{SD} ^a	Diode Forward Voltage	V _{GS} =0 V, I _{SD} =50 A	-	0.8	1.1	V
t _{rr}	Reverse Recovery Time	V _{DS} =30 V, I _{DS} =50 A, dI _{SD} /dt=100 A/μs	-	60	-	ns
Q _{rr}	Reverse Recovery Charge		-	75	-	nC
Dynamic Characteristics ^b						
C _{iss}	Input Capacitance	V _{DS} =30 V, V _{GS} =0 V, f=1 MHz	-	7880	-	pF
C _{oss}	Output Capacitance		-	1440	-	
C _{rss}	Reverse Transfer Capacitance		-	125	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =30 V, V _{GEN} =10 V, R _G =1.6 Ω, I _{DS} =50 A	-	65	-	ns
t _r	Turn-on Rise Time		-	45	-	
t _{d(off)}	Turn-off Delay Time		-	60	-	
t _f	Turn-off Fall Time		-	33	-	
Gate Charge Characteristics ^b						
Q _g	Total Gate Charge	V _{DS} =30 V, V _{GS} =10 V, I _{DS} =50 A	-	95	-	nC
Q _{gs}	Gate-Source Charge		-	31	-	
Q _{gd}	Gate-Drain Charge		-	18	-	

Notes:

- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
- Guaranteed by design, not subject to production testing.

7. Typical Characteristics

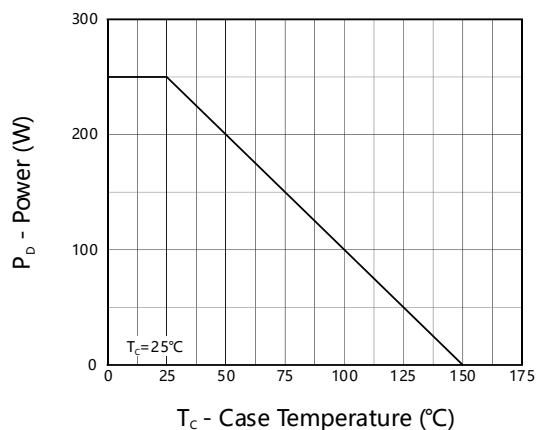


Fig 1. Power Capability

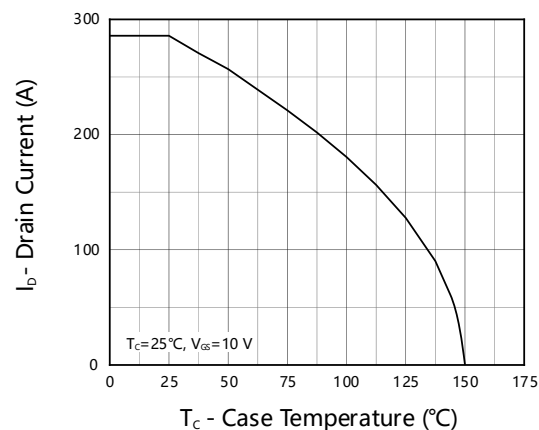


Fig 2. Current Capability

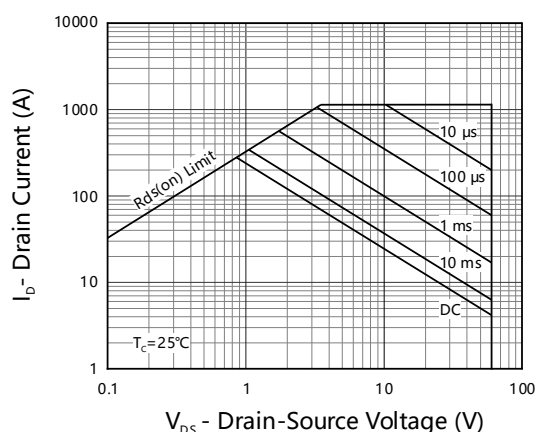


Fig 3. Safe Operation Area

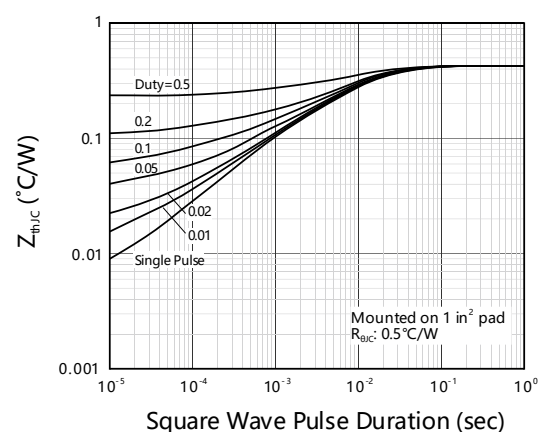


Fig 4. Transient Thermal Impedance

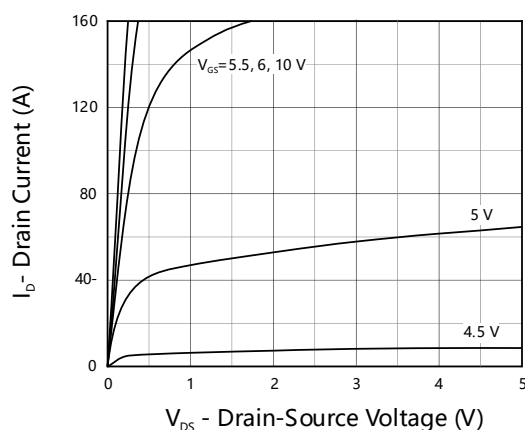


Fig 5. Output Characteristics

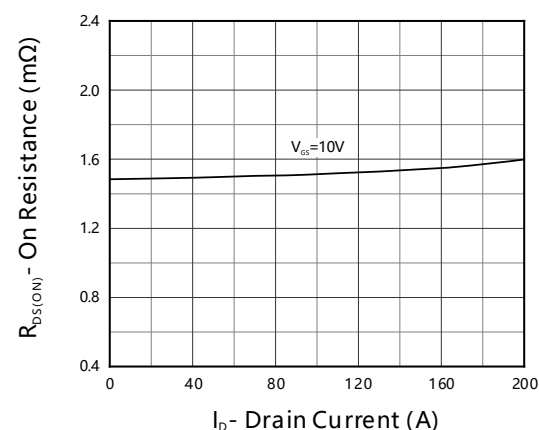


Fig 6. On Resistance

7. Typical Characteristics (cont.)

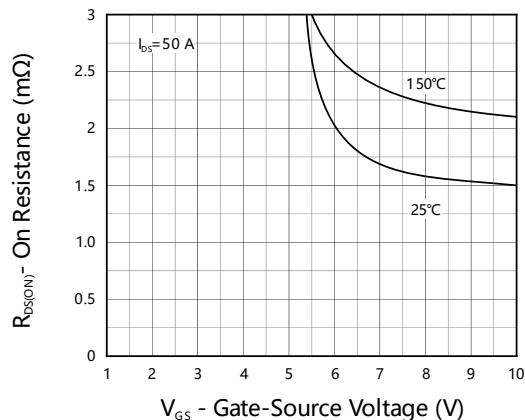


Fig 7. Transfer Characteristics

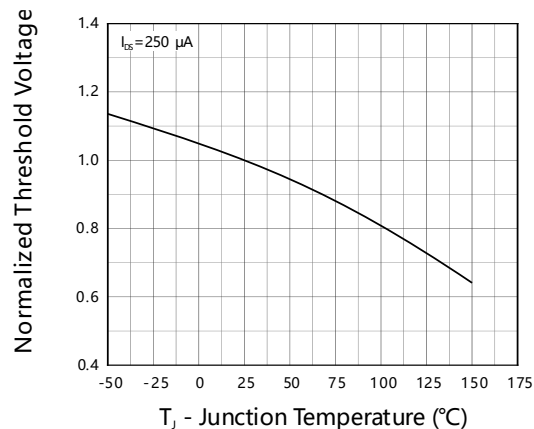


Fig 8. Normalized Threshold Voltage

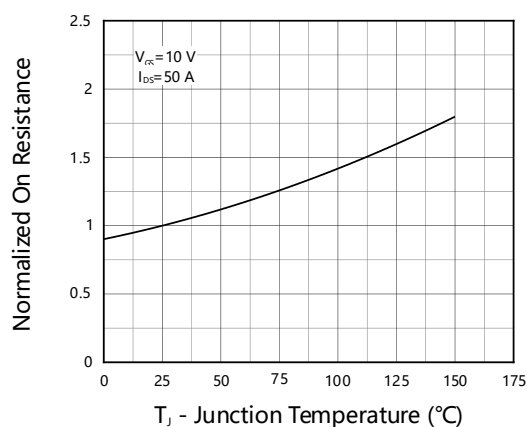


Fig 9. Normalized On Resistance

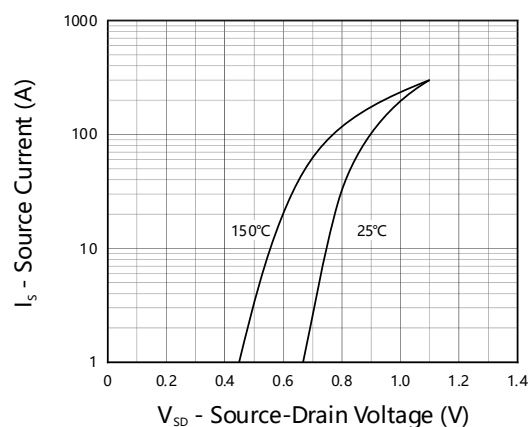


Fig 10. Diode Forward Current

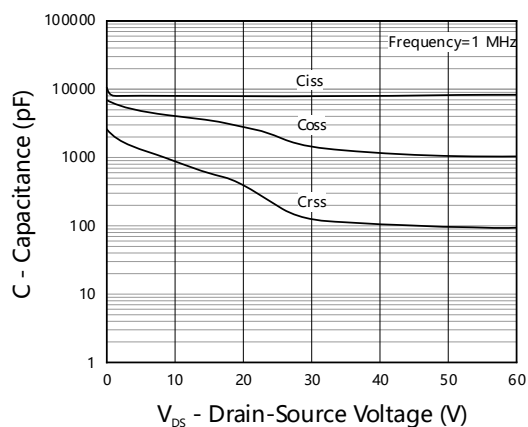


Fig 11. Capacitance

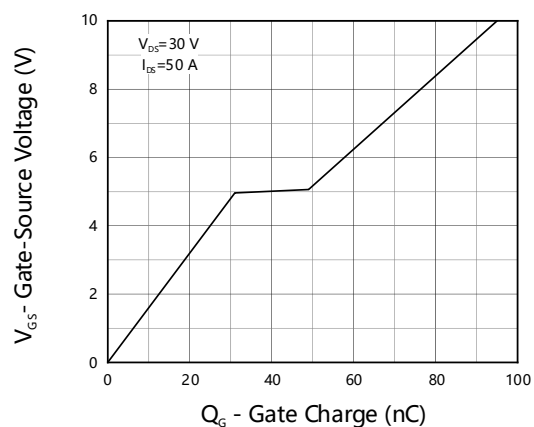
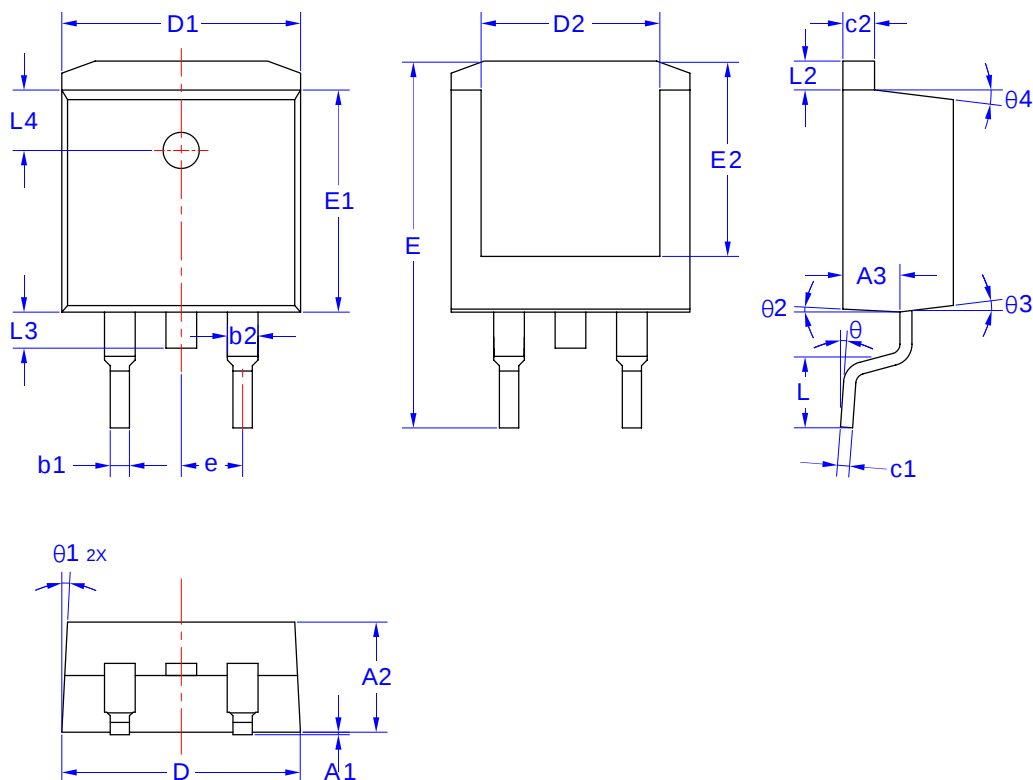


Fig 12. Gate Charge

8. Package Dimensions

TO-263 Package



Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX
A1	0.020	-	0.200
A2	4.470	4.570	4.670
A3	2.300	2.350	2.400
b1	0.750	-	0.850
b2	1.220	-	1.320
c1	0.500	-	0.550
c2	1.300	-	1.350
D	9.780	9.880	9.980
D1		9.880 REF	
D2		7.400 REF	
E	14.900	15.100	15.300
E1	9.100	9.200	9.300

Symbol	Dimensions in Millimeters		
	MIN	NOM	MAX
E2		8.100 REF	
e		5.540 REF	
L	2.100	2.300	2.500
L2	1.025	-	1.375
L3	1.300	1.500	1.700
L4	2.400	2.500	2.600
θ		0~8°	
$\theta 1$		3°	
$\theta 2$		3°	
$\theta 3$		7°	
$\theta 4$		7°	